NSN 5961-00-724-6899

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View Online at https://aerobasegroup.com/nsn/5961-00-724-6899 **Inclosure Material:** Metal **Overall Length:** 0.859 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-4 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.564 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 collector to base voltage/static/emitter open and 15.0 emitter to base voltage, static, collector open and 40.0 collector to emitter saturation voltage **Current Rating Per Characteristic:** 7.50 amperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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